TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VCX14FT,TC74VCX14FK

Low-Voltage Hex Schmitt Inverter with 3.6-V Tolerant Inputs and Outputs

The TC74VCX14FT/FK is a high-performance CMOS schmitt inverter which is guaranteed to operate from 1.2-V to 3.6-V. Designed for use in 1.5V, 1.8V, 2.5V or 3.3V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

It is also designed with over-voltage tolerant inputs and outputs up to $3.6\ V$.

Pin configuration and function are the same as the TC74VCX04 but the inputs have hysteresis and with its schmitt trigger function, the TC74VCX14 can be used as a line receivers which will receive slow input signals.

All inputs are equipped with protection circuits against static discharge.

Features

- Low-voltage operation: $V_{CC} = 1.2 \sim 3.6 \text{ V}$
- High-speed operation: $t_{pd} = 4.0 \text{ ns (max) (V}_{CC} = 3.0 \sim 3.6 \text{ V})$

 $t_{pd} = 4.3 \text{ ns (max) (VCC} = 2.3 \sim 2.7 \text{ V)}$

 $t_{pd} = 8.6 \text{ ns (max) (VCC} = 1.65 \sim 1.95 \text{ V})$

 $t_{pd} = 17.2 \text{ ns (max) (VCC} = 1.4 \sim 1.6 \text{ V})$

 $t_{pd} = 43.0 \text{ ns (max) (V}_{CC} = 1.2 \text{ V)}$

• Output current: $I_{OH}/I_{OL} = \pm 24 \text{ mA (min)} (V_{CC} = 3.0 \text{ V})$

 $: I_{OH}/I_{OL} = \pm 18 \text{ mA (min) (V}_{CC} = 2.3 \text{ V)}$

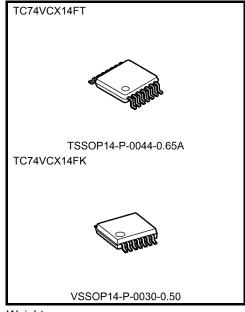
 $: I_{OH}/I_{OL} = \pm 6 \text{ mA (min) (V}_{CC} = 1.65 \text{ V)}$

 $: I_{OH}/I_{OL} = \pm 2 \text{ mA (min) (V}_{CC} = 1.4 \text{ V})$

- Latch-up performance: -300 mA
- ESD performance: Machine model ≥ ±200 V

Human body model $\geq \pm 2000 \text{ V}$

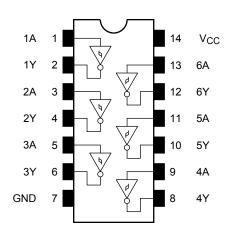
- Package: TSSOP and VSSOP (US)
- Power-down protection provided on all inputs and outputs



Weight

TSSOP14-P-0044-0.65A : 0.06 g (typ.) VSSOP14-P-0030-0.50 : 0.02 g (typ.)

Pin Assignment (top view)



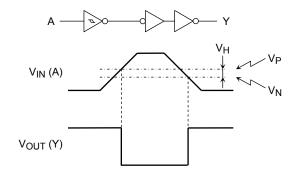
IEC Logic Symbol

1A(1)	D	(2) 1Y
2A(3)		(4) 2Y
3A <u>(5</u>)		(6) 3Y
4A (9)		(8) 4Y
5A (11)		(10) 5Y
6A <u>(13</u>	3)		(12) 6Y

Truth Table

Inputs	Outputs
Α	Υ
L	Н
Н	L

System Diagram and Waveforms



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit	
Power supply voltage	V _{CC}	-0.5~4.6	V	
DC input voltage	V _{IN}	-0.5~4.6	V	
DC output voltage	V _{OUT}	-0.5~4.6 (Note 2)	V	
DC dulput voltage	VOU1	-0.5~V _{CC} + 0.5 (Note 3)		
Input diode current	l _{IK}	-50	mA	
Output diode current	lok	±50 (Note 4)	mA	
DC output current	lout	±50	mA	
Power dissipation	PD	180	mW	
DC V _{CC} /ground current	I _{CC} /I _{GND}	±100	mA	
Storage temperature	T _{stg}	−65~150	°C	

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: $V_{CC} = 0 V$

Note 3: High or low state. IOUT absolute maximum rating must be observed.

Note 4: $V_{OUT} < GND$, $V_{OUT} > V_{CC}$

Operating Ranges (Note 1)

Characteristics	Symbol	Rating	Unit	
Power supply voltage	V _{CC}	1.2~3.6	V	
Input voltage	V _{IN}	-0.3~3.6	V	
Output voltage	V	0~3.6 (Note 2)	V	
Output voltage	V _{OUT}	0~V _{CC} (Note 3)		
		±24 (Note 4)		
Output current	la/la.	±18 (Note 5)	mA	
Output current	I _{OH} /I _{OL}	±6 (Note 6)	MA	
		±2 (Note 7)		
Operating temperature	T _{opr}	-40~85	°C	

Note 1: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either VCC or GND.

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Note 2: $V_{CC} = 0 V$

Note 3: High or low state

Note 4: $V_{CC} = 3.0 \sim 3.6 \text{ V}$

Note 5: $V_{CC} = 2.3 \sim 2.7 \text{ V}$

Note 6: $V_{CC} = 1.65 \sim 1.95 \text{ V}$

Note 7: $V_{CC} = 1.4 \sim 1.6 \text{ V}$



Electrical Characteristics

DC Characteristics (Ta = -40 to 85°C, 2.7 V < $V_{CC} \le 3.6$ V)

Characteristic	c	Symbol	Test Co	Test Condition		Min	Min Max	Unit
Characteristic	3	Symbol	Test Co			IVIIII		Onit
	H-level	V _P			3.6	_	2.2	V
Input voltage	i i-ievei	VP		-	3.0	_	2.0	V
input voitage	L-level	V			3.6	0.8	_	V
	L-level	V _N	_	-	3.0	0.7	_	V
Liveteresia veltaga		V			3.6	0.3	1.2	V
Hysteresis voltage		V _H	_	_		0.3	1.2	V
	H-level			I _{OH} = -100 μA	2.7~3.6	V _{CC} - 0.2	_	V
		V _{OH}	$V_{IN} = V_{IL}$	I _{OH} = -12 mA	2.7	2.2	_	
				I _{OH} = -18 mA	3.0	2.4	_	
Output voltage				I _{OH} = -24 mA	3.0	2.2	_	
				$I_{OL} = 100 \ \mu A$	2.7~3.6	_	0.2	
	L-level	V _{OL}	Mar. Mar.	$I_{OL} = 12 \text{ mA}$	2.7	_	0.4	
	L-level	VOL	$V_{IN} = V_{IH}$	$I_{OL} = 18 \text{ mA}$	3.0	_	0.4	
				$I_{OL} = 24 \text{ mA}$	3.0	_	0.55	
Input leakage current		I _{IN}	V _{IN} = 0 to 3.6 V		2.7~3.6		±5.0	μА
Power-off leakage current	t	I _{OFF}	V_{IN} , $V_{OUT} = 0$ to 3.6 \	/	0	_	10.0	μА
Quioscont supply current		loo	V _{IN} = V _{CC} or GND		2.7~3.6	_	20.0	
Quiescent supply current		Icc	$V_{CC} \le V_{IN} \le 3.6 \text{ V}$	/ _{CC} ≤ V _{IN} ≤ 3.6 V		_	±20.0	μА
Increase in I _{CC} per input		Δl _{CC}	$V_{IH} = V_{CC} - 0.6 V$		2.7~3.6	_	750	

DC Characteristics (Ta = -40 to 85°C, 2.3 V \leq V_{CC} \leq 2.7 V)

Characteristic	20	Symbol	Tost Co	ndition		Min	Max	Unit
Characteristic	.5	Symbol	Test Co	Test Condition		IVIIII	IVIAX	Offic
Input voltage H-level L-level		V _P	_	-	2.3	_	1.6	V
		V _N	_	-	2.3	0.5	_	V
Hysteresis voltage		VH	_	-	2.3	0.3	1.0	V
				I _{OH} = -100 μA	2.3~2.7	V _{CC} - 0.2	_	
	H-level	V _{OH}	$V_{IN} = V_{IL}$	$I_{OH} = -6 \text{ mA}$	2.3	2.0	_	V
				I _{OH} = -12 mA	2.3	1.8	_	
Output voltage				$I_{OH} = -18 \text{ mA}$	2.3	1.7	_	
				I _{OL} = 100 μA	2.3~2.7	_	0.2	
	L-level	V_{OL}	$V_{IN} = V_{IH}$	I _{OL} = 12 mA	2.3	_	0.4	
				I _{OL} = 18 mA	2.3	_	0.6	
Input leakage current		I _{IN}	V _{IN} = 0 to 3.6 V	•	2.3~2.7	_	±5.0	μА
Power-off leakage curren	t	I _{OFF}	V _{IN} , V _{OUT} = 0 to 3.6 V		0	_	10.0	μА
Quiocont aunaly current		laa	V _{IN} = V _{CC} or GND		2.3~2.7		20.0	^
Quiescent supply current		Icc	$V_{CC} \le V_{IN} \le 3.6 \text{ V}$		2.3~2.7	_	±20.0	μА



DC Characteristics (Ta = -40 to 85°C, 1.65 V \leq V_{CC} < 2.3 V)

Characteristic	e	Symbol	Test Con	dition		Min	Max	Unit
Onaracteristic	3	Oymbor	rest con	rest condition		IVIIII	IVIAX	Offic
Input voltage	H-level	V _P	_		1.65	_	1.4	V
mpat voltage	L-level	VN	_		1.65	0.25	_	V
Hysteresis voltage		VH	_		1.65	0.2	0.95	V
	H-level	V _{OH}	$V_{IN} = V_{IL}$	I _{OH} = -100 μA	1.65~2.3	V _{CC} - 0.2	_	٧
Output voltage				$I_{OH} = -6 \text{ mA}$	1.65	1.25	_	
	L-level Voi	V _{OL}	$V_{IN} = V_{IH}$	$I_{OL} = 100 \ \mu A$	1.65~2.3		0.2	V
	L-level	VOL		$I_{OL} = 6 \text{ mA}$	1.65		0.3	V
Input leakage current		I _{IN}	V _{IN} = 0 to 3.6 V		1.65~2.3		±5.0	μΑ
Power-off leakage current	t	l _{OFF}	V_{IN} , $V_{OUT} = 0$ to 3.6 V		0	_	10.0	μΑ
Quiggaent gunnly gurrent			V _{IN} = V _{CC} or GND		1.65~2.3		20.0	
Quiescent supply current		Icc	$V_{CC} \le V_{IN} \le 3.6 \text{ V}$		1.65~2.3	_	±20.0	μΑ

DC Characteristics (Ta = -40 to 85° C, 1.4 V \leq V_{CC}< 1.65 V)

Characteristic	s.	Symbol	Test Co	ndition		Min	Max	Unit
Onardotenstio		Cymbol	rest oblidition		V _{CC} (V)	141111	Wax	Onic
Input voltage H-level		V _P	_		1.4	_	1.2	V
	L-level	V _N	_		1.4	0.2	_	V
Hysteresis voltage		VH	_		1.4	0.2	0.9	V
	H-level	V _{OH}	$V_{IN} = V_{IL}$	I _{OH} = -100 μA	1.4~1.65	V _{CC} - 0.2	_	v v
Output voltage				$I_{OH} = -2 \text{ mA}$	1.4	1.05	_	
	L-level	V/	$V_{IN} = V_{IH}$	$I_{OL} = 100 \mu A$	1.4~1.65	_	0.05	
	L-level	V _{OL}		I _{OL} = 2 mA	1.4	_	0.35	
Input leakage current		I _{IN}	V _{IN} = 0 to 3.6 V	•	1.4~1.65	_	±5.0	μА
Power-off leakage current	er-off leakage current I _{OFF} V _{IN} , V _{OUT} = 0 to 3.6 V		0	_	10.0	μА		
Quiescent supply current		1	V _{IN} = V _{CC} or GND		1.4~1.65	_	20.0	
		Icc	$V_{CC} \le V_{IN} \le 3.6 \text{ V}$		1.4~1.65		±20.0	μА



DC Characteristics (Ta = -40 to 85° C, $1.2 \text{ V} \leq \text{V}_{CC} < 1.4 \text{ V}$)

Characteristics		Symbol	Test Condition		V _{CC} (V)	Min	Max	Unit
Input voltage H-level		V _P	_		1.2	_	1.1	V
input voitage	L-level	V _N	_		1.2	0.05		V
Hysteresis voltage		V _H	_		1.2	0.2	0.9	>
Output voltage	H-level	V _{OH}	$V_{IN} = V_{IL}$	$I_{OH} = -100 \mu A$	1.2	V _{CC} - 0.1		٧
	L-level	V _{OL}	$V_{IN} = V_{IH}$	$I_{OL} = 100 \mu A$	1.2	_	0.05	V
Input leakage current		I _{IN}	V _{IN} = 0 to 3.6 V		1.2		±5.0	μΑ
Power-off leakage current		loff	V_{IN} , $V_{OUT} = 0$ to 3.6 V		0		10.0	μΑ
		laa	$V_{IN} = V_{CC}$ or GND		1.2		20.0	
Quiescent supply current		ICC	$V_{CC} \le V_{IN} \le 3.6 \text{ V}$		1.2	_	±20.0	μА

AC Characteristics (Ta = -40 to 85° C, input: $t_r = t_f = 2.0$ ns) (Note 1)

Characteristics	Symbol	Test Condition Vcc (V)			Min	Max	Unit
			C. 15 p. 2 k0	1.2	3.0	43.0	
	+		$C_L = 15 \text{ pF}, R_L = 2 \text{ k}\Omega$	1.5 ± 0.1	2.0	17.2	
Propagation delay time	t _{pLH} t _{pHL}	Figure 1, Figure 2		1.8 ± 0.15	1.5	8.6	ns
	чрнц		$C_L = 30$ pF, $R_L = 500$ Ω	2.5 ± 0.2	8.0	4.3	
				3.3 ± 0.3	0.6	4.0	
			$C_{\parallel} = 15 \text{ pF}, R_{\parallel} = 2 \text{ k}\Omega$	1.2		1.5	
	.		CL = 15 pr, RL = 2 KΩ	1.5 ± 0.1		1.5	
Output to output skew	tosLH	(Note 2)		1.8 ± 0.15	_	0.5	ns
	t _{osHL}		$C_L = 30 \text{ pF}, R_L = 500 \Omega$	2.5 ± 0.2		0.5	
				3.3 ± 0.3	_	0.5	

Note 1: For $C_L = 50$ pF, add approximately 300 ps to the AC maximum specification.

Note 2: Parameter guaranteed by design. $(t_{OSLH} = |t_{DLHm} - t_{DLHn}|, \, t_{OSHL} = |t_{DHLm} - t_{DHLn}|)$



Dynamic Switching Characteristics (Ta = 25°C, input: $t_r = t_f$ = 2.0 ns, C_L = 30 pF)

Characteristics	Symbol	Test Condition V _{CC} (V)		Тур.	Unit
Quiet output maximum dynamic V _{OL}		V _{IH} = 1.8 V, V _{IL} = 0 V (Note		0.25	V
	V _{OLP}	V _{IH} = 2.5 V, V _{IL} = 0 V (Note	2.5	0.6	V
		V _{IH} = 3.3 V, V _{IL} = 0 V (Note	3.3	0.8	V
	V _{OLV}	$V_{IH} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$ (Note	1.8	-0.25	V
Quiet output minimum dynamic V _{OL}		$V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$ (Note	2.5	-0.6	V
		$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ (Note	3.3	-0.8	V
	V _{OHV}	$V_{IH} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$ (Note	1.8	1.5	V
Quiet output minimum dynamic V _{OH}		$V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$ (Note	2.5	1.9	V
		$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ (Note	3.3	2.2	V

Note: Parameter guaranteed by design.

Capacitive Characteristics (Ta = 25°C)

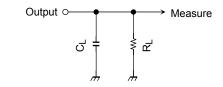
Characteristics	Symbol		Test Condition		V _{CC} (V)	Тур.	Unit
Input capacitance	C _{IN}		_		1.8, 2.5, 3.3	6	pF
Power dissipation capacitance	C _{PD}	f _{IN} = 10 MHz		(Note)	1.8, 2.5, 3.3	20	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/6 \text{ (per gate)}$

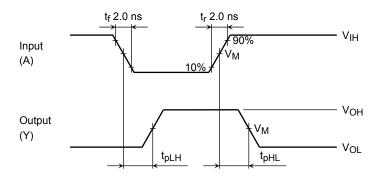
AC Test Circuit



Symbol	V _{CC}		
	$\begin{array}{c} 3.3 \pm 0.3 \text{ V} \\ 2.5 \pm 0.2 \text{ V} \\ 1.8 \pm 0.15 \text{ V} \end{array}$	1.5 ± 0.1 V 1.2V	
R_{L}	500 Ω	2 kΩ	
CL	30 pF	15 pF	

Figure 1

AC Waveform



Symbol	Vcc					
	$3.3\pm0.3~\textrm{V}$	$2.5\pm0.2\textrm{V}$	1.8 ± 0.15 V	$1.5\pm0.1~\textrm{V}$	1.2 V	
V_{IH}	2.7 V	V _{CC}	V _{CC}	V _{CC}	V _{CC}	
V _M	1.5 V	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	

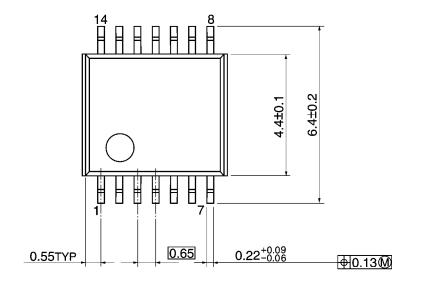
Figure 2 t_{pLH}, t_{pHL}

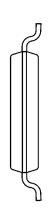
8

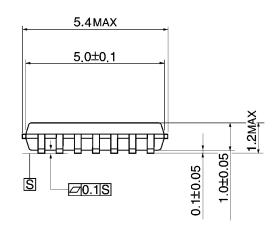
Package Dimensions

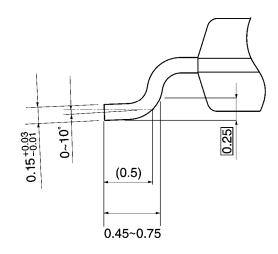
TSSOP14-P-0044-0.65A

Unit: mm





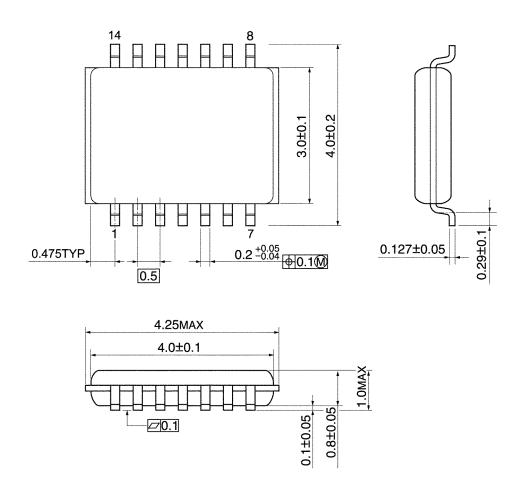




Weight: 0.06 g (typ.)

Package Dimensions

VSSOP14-P-0030-0.50 Unit: mm



Weight: 0.02 g (typ.)

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